

TS/TC Type

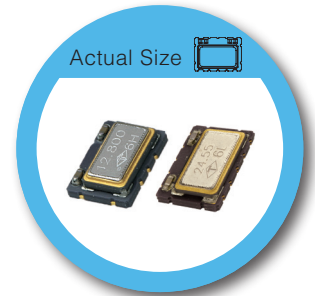
7.0 x 5.0 mm SMD High Precision Voltage Controlled Temperature Compensated Crystal Oscillator

FEATURE

- Typical 7.0 x 5.0 x 1.85 mm ceramic SMD package.
- High Precision for $-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$, $\pm 0.28\text{ppm}$.
- CMOS and Clipped Sine wave (without DC-cut capacitor) output optional.

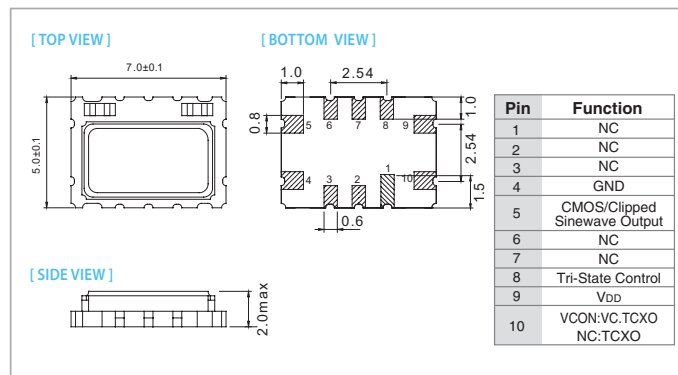
TYPICAL APPLICATION

- Femtocell , Base Stations
- WLAN/WiMax/WIFI, Wireless Communications
- Mobile Phone

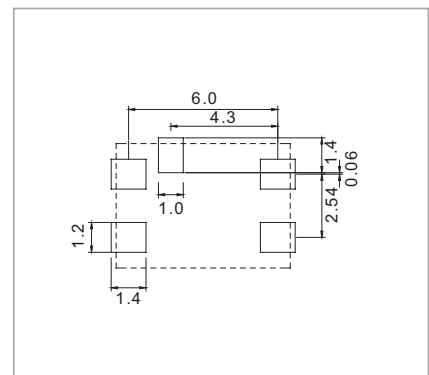


RoHS Compliant Standard

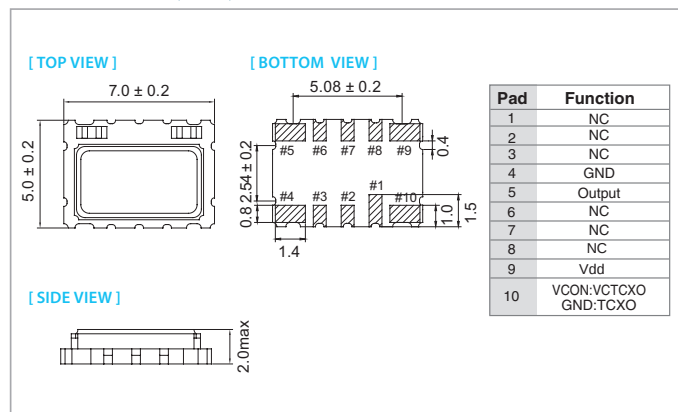
DIMENSION (mm) - TS



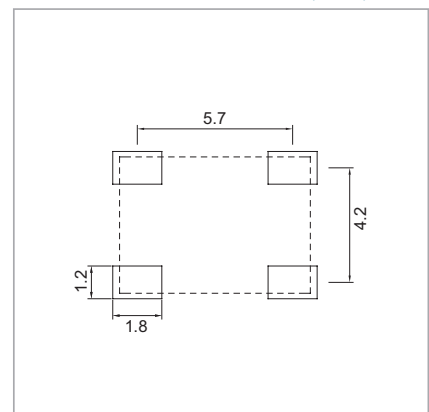
SOLDER PAD LAYOUT (mm)



DIMENSION (mm) - TC



SOLDER PAD LAYOUT (mm)



FREQ. STABILITY vs. TEMP. RANGE

Temp. (°C)	ppm	±0.05	±0.1	±0.14	±0.2	±0.28	±0.37	±0.5
0 ~ +55		○	○	○	○	○	○	○
-10 ~ +60		○	○	○	○	○	○	○
-20 ~ +70		△	○	○	○	○	○	○
-40 ~ +85		×	×	×	△	○	○	○

* ○: Available △: Conditional X: Not available

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7.0 x 5.0 mm SMD High Precision Voltage Controlled Temperature Compensated Crystal Oscillator

ELECTRICAL SPECIFICATION

Parameter	5.0 V		3.3 V		Unit	
	Min.	Max.	Min.	Max.		
Supply Voltage Variation (VDD) 5%	4.75	5.25	3.135	3.465	V	
Frequency Range	5	40	5	40	MHz	
Standard Frequency (for CMOS)	5, 6.4, 8, 8.192, 10, 12.5, 12.8, 16, 16.384, 19.44, 25					
Standard Frequency (for Clipped Sine)	8.192, 10, 12.5, 12.8, 16, 16.384, 19.44, 25					
Frequency Tolerance*	—	±2.0	—	±2.0	ppm	
Frequency Stability						ppm
Vs Supply Voltage (±5%) change (for CMOS)	—	±0.3	—	±0.3		
Vs Load (±10%) change	—	±0.2	—	±0.2		
Vs Aging (@ 1st year)	—	±1.0	—	±1.0		
Supply Current (CMOS output)	—	6	—	6	mA	
Supply Current (Clipped Sine Wave)	—	3.5	—	3.5		
Output Level (CMOS)						V
Output High (Logic “1”)	90%VDD	—	90%VDD	—		
Output Low (Logic “0”)	—	10%VDD	—	10%VDD		
Duty	45	55	45	55		
Output Level (Clipped Sine Wave)	0.8	—	0.8	—	Vp-p	
Load (CMOS)	15pF		15pF			
Load (Clipped Sine Wave)	10 KΩ // 10pF		10 KΩ // 10pF			
Control Voltage Range (VCTCXO)	0.5	2.5	0.5	2.5	V	
Pulling Range (VCTCXO)	±5.0	—	±5.0	—	ppm	
Vc Input Impedance (VCTCXO)	100	—	100	—	KΩ	
Phase Noise @ 12.8 MHz						dBc/Hz
100 Hz	-120		-120			
1 KHz	-140		-140			
10 KHz	-148		-148			
Start time	—	2	—	2	mSec	
Tri-State (option)						V
Disable	—	0.3VDD	—	0.3VDD		
Enable	0.7VDD	—	0.7VDD	—		
Storage Temp. Range	-55	125	-55	125	°C	

Standard frequencies are frequencies which the crystal has been designed and does not imply a stock position.

*Frequency at 25°C, 1 hour after reflow.

Packing: Tape & Reel 1000/3000pcs per Reel.